# UTC UNISONIC TECHNOLOGIES CO., LTD

# 8050S

### NPN SILICON TRANSISTOR

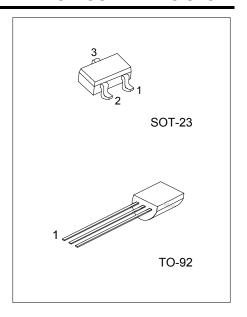
# LOW VOLTAGE HIGH **CURRENT SMALL SIGNAL** NPN TRANSISTOR

#### DESCRIPTION

The UTC 8050S is a low voltage high current small signal NPN transistor, designed for Class B push-pull audio amplifier and general purpose applications.

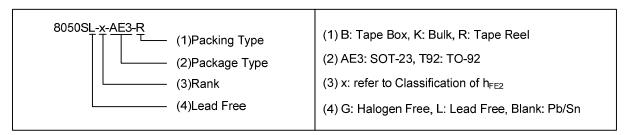
#### **FEATURES**

- \*Collector current up to 700mA
- \*Collector-Emitter voltage up to 20V
- \*Complementary to UTC 8550S

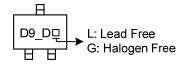


#### ORDERING INFORMATION

| Ordering Number |                   |                | Dookogo | Pin Assignment |   |   | Dooking   |  |
|-----------------|-------------------|----------------|---------|----------------|---|---|-----------|--|
| Normal          | Lead Free Plating | Halogen-Free   | Package | 1              | 2 | 3 | Packing   |  |
| 8050S-x-AE3-R   | 8050SL-x-AE3-R    | 8050SG-x-AE3-R | SOT-23  | Е              | В | С | Tape Reel |  |
| 8050S-x-T92-B   | 8050SL-x-T92-B    | 8050SG-x-T92-B | TO-92   | Е              | С | В | Tape Box  |  |
| 8050S-x-T92-K   | 8050SL-x-T92-K    | 8050SG-x-T92-K | TO-92   | Е              | С | В | Bulk      |  |



MARKING (For SOT-23 Package)



# ■ ABSOLUTE MAXIMUM RATING (Ta=25°C, unless otherwise specified)

| PARAMETER                       |        | SYMBOL           | RATINGS    | UNIT |
|---------------------------------|--------|------------------|------------|------|
| Collector-Base Voltage          |        | $V_{CBO}$        | 30         | V    |
| Collector-Emitter Voltage       |        | $V_{CEO}$        | 20         | V    |
| Emitter-Base Voltage            |        | $V_{EBO}$        | 5          | V    |
| Collector Current               |        | Ic               | 700        | mA   |
| Calle star Dissipation/Ta-25°C) | SOT-23 | P <sub>C</sub>   | 350        | mW   |
| Collector Dissipation(Ta=25°C)  | TO-92  |                  | 1          | W    |
| Junction Temperature            |        | TJ               | +150       | °C   |
| Storage Temperature             |        | T <sub>STG</sub> | -40 ~ +150 | °C   |

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

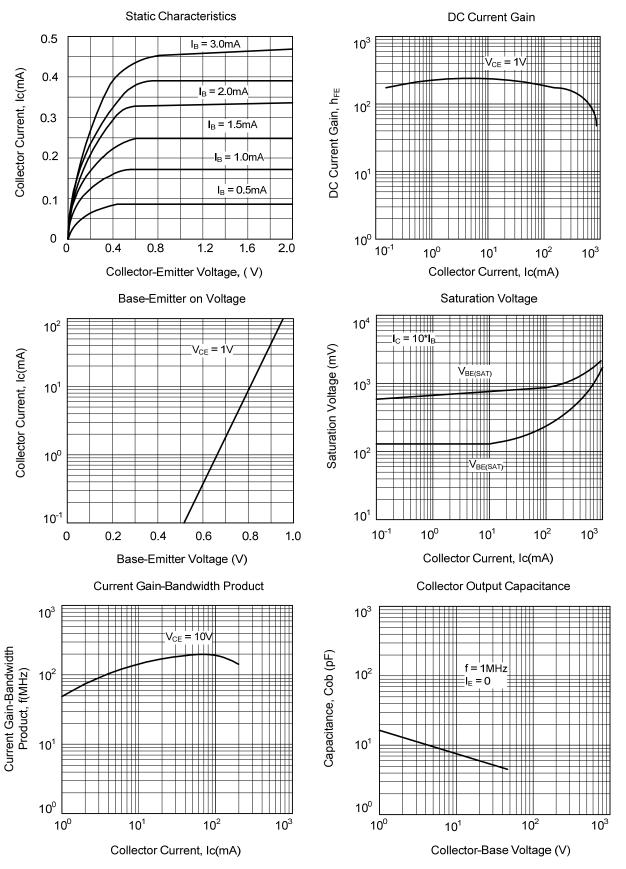
## ■ ELECTRICAL CHARACTERISTICS (Ta=25°C, unless otherwise specified)

| PARAMETER                            | SYMBOL                | TEST CONDITIONS                               |     | TYP | MAX | UNIT |
|--------------------------------------|-----------------------|---|-----|-----|-----|------|
| Collector-Base Breakdown Voltage     | $BV_{CBO}$            | $I_C = 100 \mu A, I_E = 0$                    |     |     |     | V    |
| Collector-Emitter Breakdown Voltage  | $BV_CEO$              | $I_{\rm C} = 1 {\rm mA}, I_{\rm B} = 0$       | 20  |     |     | V    |
| Emitter-Base Breakdown Voltage       | $BV_{EBO}$            | $I_E = 100 \mu A, I_C = 0$                    | 5   |     |     | V    |
| Collector Cut-Off Current            | I <sub>CBO</sub>      | $V_{CB} = 30V, I_{E} = 0$                     |     |     | 1   | uA   |
| Emitter Cut-Off Current              | I <sub>EBO</sub>      | $V_{EB} = 5V, I_{C} = 0$                      |     |     | 100 | nA   |
|                                      | h <sub>FE1</sub>      | $V_{CE} = 1V$ , $I_C = 1mA$                   | 100 |     | 400 |      |
| DC Current Gain(note)                | h <sub>FE2</sub>      | $V_{CE} = 1V, I_{C} = 150 \text{ mA}$         | 120 |     |     |      |
|                                      | h <sub>FE3</sub>      | $V_{CE} = 1V, I_{C} = 500mA$                  | 40  |     |     |      |
| Collector-Emitter Saturation Voltage | V <sub>CEO(SAT)</sub> | $I_C = 500 \text{mA}, I_B = 50 \text{mA}$     |     |     | 0.5 | V    |
| Base-Emitter Saturation Voltage      | V <sub>BEO(SAT)</sub> | I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA |     |     | 1.2 | V    |
| Base-Emitter Saturation Voltage      | $V_{BEO(SAT)}$        | $V_{CE} = 1V$ , $I_C = 10mA$                  |     |     | 1.0 | V    |
| Current Gain Bandwidth Product       | f <sub>T</sub>        | V <sub>CE</sub> = 10V, I <sub>C</sub> = 50mA  | 100 |     |     | MHz  |
| Output Capacitance                   | Cob                   | $V_{CB} = 10V, I_{E} = 0, f = 1MHz$           |     | 9.0 |     | pF   |

## ■ CLASSIFICATION OF h<sub>FE2</sub>

| RANK  | С       | D       | Е       |
|-------|---------|---------|---------|
| RANGE | 120-200 | 160-300 | 280-400 |

#### ■ TYPICAL CHARACTERISTICS



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